



# Single Phase Glass Passivated Silicon Bridge Rectifier

 $V_{RRM} = 600 \text{ V} -1000 \text{ V}$  $I_{O} = 4 \text{ A}$ 

#### **Features**

 Plastic package has Underwriters Laboratory Flammability Classification 94V-0

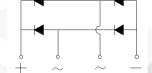
- This series is UL listed under the Recognized
- · Glass passivated chip junction
- · High case dielectric strength
- Typical I<sub>R</sub> less than 0,1 A
- High surge current capability
- · Ideal for printed circuit boards
- · Not ESD Sensitive



Case: Molded plastic body over passivated junctions

Terminals: Plated leads, solderable per MIL-STD-750 Method 2026.

Weight: 0.071 oz, 2.0 g







Maximum ratings at Tc = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	GBL06	GBL08	GBL10	Unit
Repetitive peak reverse voltage	$V_{RRM}$		600	800	1000	V
RMS reverse voltage	V <sub>RMS</sub>		420	560	700	V
DC blocking voltage	$V_{DC}$		600	800	1000	V
Operating temperature	T <sub>j</sub>		-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	$T_{stg}$		-55 to 150	-55 to 150	-55 to 150	°C

#### Electrical characteristics at Tc = 25 °C, unless otherwise specified

Single phase, half sine wave, 60 Hz, resistive or inductive load.

For capacitive load derate current by 20%.

Parameter	Symbol	Conditions	GBL06	GBL08	GBL10	Unit
Maximum average forward rectified current	I <sub>O</sub>	T <sub>c</sub> = 50 °C (Note 1)	4.0	4.0	4.0	Α
		$T_c = 40  ^{\circ}\text{C}  (\text{Note 2})$	3.0	3.0	3.0	
Peak forward surge current	I <sub>FSM</sub>	t <sub>p</sub> = 8.3 ms, half sine	135	135	135	Α
Maximum instantaneous forward voltage drop per leg	$V_{F}$	I <sub>F</sub> = 4 A	1.1	1.1	1.1	V
Maximum DC reverse current at rated DC blocking voltage per leg	I <sub>R</sub>	T <sub>a</sub> = 25 °C	5	5	5	μΑ
		T <sub>a</sub> = 125 °C	500	500	500	
Rating for fusing	l <sup>2</sup> t	t < 8.3 ms	75	75	75	A <sup>2</sup> sec
Typical junction capacitance per leg (Note 3)	C <sub>j</sub>		40	40	40	pF
Typical thermal resistance per leg	R <sub>oJA</sub>	(Note 1)	22	22	22	°C/W
	$R_{\Theta JL}$	(Note 2)	3.5	3.5	3.5	

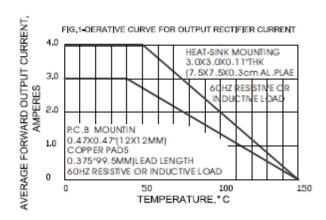
<sup>&</sup>lt;sup>1</sup> - Unit mounted on 3.0" x 3.0" x 0.11" (75 mm x 75 mm x 3 mm) Al plate

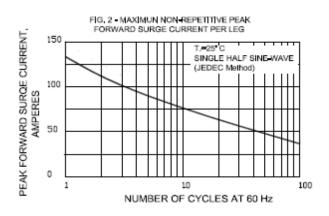
<sup>&</sup>lt;sup>2</sup> - Unit mounted on P.C.B. At 0.375" (9.5 mm) lead length and 0.5" x 0.5" (12 mm x 12 mm)

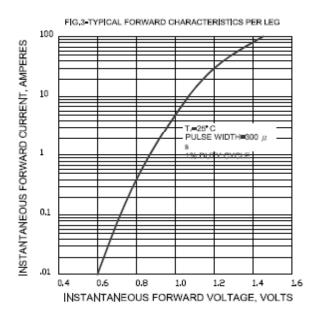
<sup>&</sup>lt;sup>3</sup> - Measured at 1.0 MHz and applied reverse bias of 4.0 V

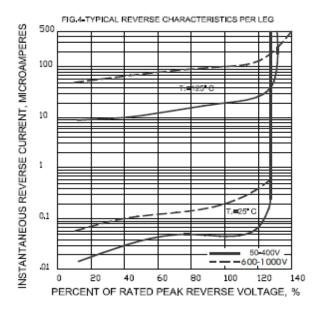
## GBL06 thru GBL10

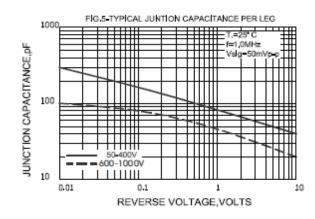


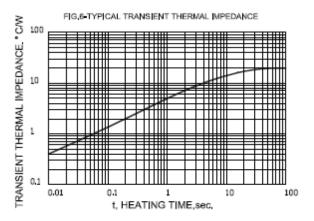








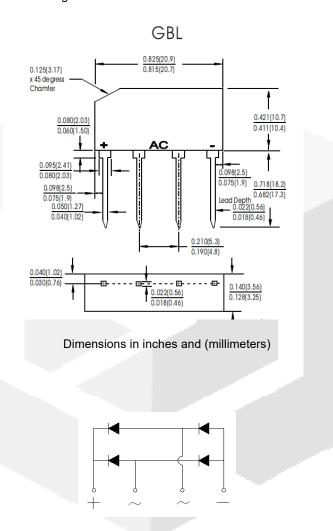






### Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



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GBL06 GBL08 GBL10